

New iLGAD detector development at CNM

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We will present the first technological developments at CNM to fabricate a new p-on-p position-sensitive detector with low signal amplification useful as well for timing applications. This device is based on a double-sided LGAD with pad-like multiplication structure in the back-side and ohmic read out in the front side. It is has been named “inverted”LGAD (iLGAD).

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